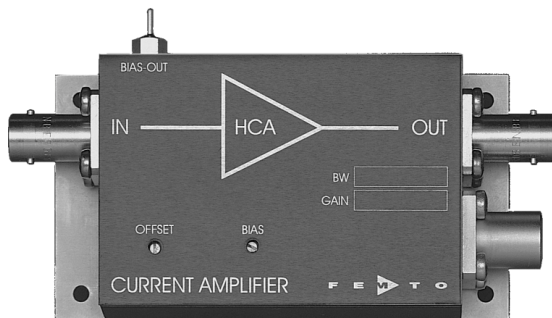


# High Speed Current Amplifier



<p>Features</p>	<ul style="list-style-type: none"> <li>• <b>Bandwidth and Frequency Response Independent of Detector Capacitance (up to 2 nF)</b></li> <li>• <b>Low Noise 3.5 pA/√Hz Equivalent Input Noise Current</b></li> <li>• <b>Bandwidth DC ... 1 MHz</b></li> <li>• <b>Transimpedance (Gain) 1 x 10<sup>6</sup> V/A</b></li> <li>• <b>Protection against ± 3.5 kV Transients</b></li> </ul>	
<p>Applications</p>	<ul style="list-style-type: none"> <li>• <b>Photodiode and Photomultiplier Amplifier</b></li> <li>• <b>Spectroscopy</b></li> <li>• <b>Charge Amplifier</b></li> <li>• <b>Ionisation Detectors</b></li> <li>• <b>Preamplifier for Lock-Ins, A/D Converters, etc.</b></li> </ul>	
<p>Specifications</p>	<p>Test Conditions</p> <p><math>V_s = \pm 15 \text{ V}, T_a = 25^\circ\text{C}</math></p> <p>Gain</p> <p>Transimpedance</p> <p>Gain Accuracy</p> <p>Frequency Response</p> <p>Lower Cut-Off Frequency</p> <p>Upper Cut-Off Frequency (- 3 dB)</p> <p>Rise / Fall Time (10 % - 90 %)</p> <p>Gain Flatness</p> <p>Input</p> <p>Equ. Input Noise Current</p> <p>Equ. Input Noise Voltage</p> <p>Input Bias Current</p> <p>Input Bias Current Drift</p> <p>Offset Current Compensation</p> <p>Input Current Range</p> <p>Input Offset Voltage</p> <p>DC Input Impedance</p> <p>Output</p> <p>Output Voltage Range</p> <p>Output Impedance</p> <p>Bias Output</p> <p>Bias Output Voltage Range</p> <p>Bias Output Impedance</p>	<p><math>V_s = \pm 15 \text{ V}, T_a = 25^\circ\text{C}</math></p> <p><math>1 \times 10^6 \text{ V/A (@ } 50 \text{ } \Omega \text{ load)}</math></p> <p><math>\pm 1 \%</math></p> <p>DC</p> <p>1 MHz</p> <p>350 ns</p> <p><math>\pm 0.3 \text{ dB}</math></p> <p>3.5 pA/√Hz (@ 100 kHz)</p> <p>0.8 nV/√Hz (@ 100 kHz)</p> <p>18 μA typ.</p> <p>0.8 nA / K</p> <p><math>\pm 6 \text{ } \mu\text{A}</math> adjustable by offset trimpot</p> <p><math>\pm 1.5 \text{ } \mu\text{A}</math> (for linear amplification)</p> <p>3 mV</p> <p>50 Ω (virtual) // 5 pF</p> <p><math>\pm 1.5 \text{ V (@ } 50 \text{ } \Omega \text{ load)}</math> for linear operation and low harmonic distortion</p> <p>50 Ω (terminate with 50 Ω load for best performance)</p> <p><math>\pm 12 \text{ V}</math>, adjustable by bias trimpot</p> <p>10 kΩ // 1 μF</p>

## High Speed Current Amplifier

Specifications (continued)

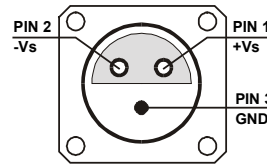
Power Supply	Supply Voltage	$\pm 15\text{ V}$
	Supply Current	$\pm 50\text{ mA typ.}$ (depends on operating conditions, recommended power supply capability minimum $\pm 150\text{ mA}$ )
Case	Weight	210 g (0.5 lbs)
	Material	AlMg4.5Mn, nickel-plated
Temperature Range	Storage Temperature	$-40 \dots +100\text{ }^\circ\text{C}$
	Operating Temperature	$0 \dots +60\text{ }^\circ\text{C}$

Absolute Maximum Ratings

Input Voltage	$\pm 5\text{ V}$
Input Voltage Transient	$\pm 3.5\text{ kV}$ (pulsewidth 10 ns)
Power Supply Voltage	$\pm 22\text{ V}$

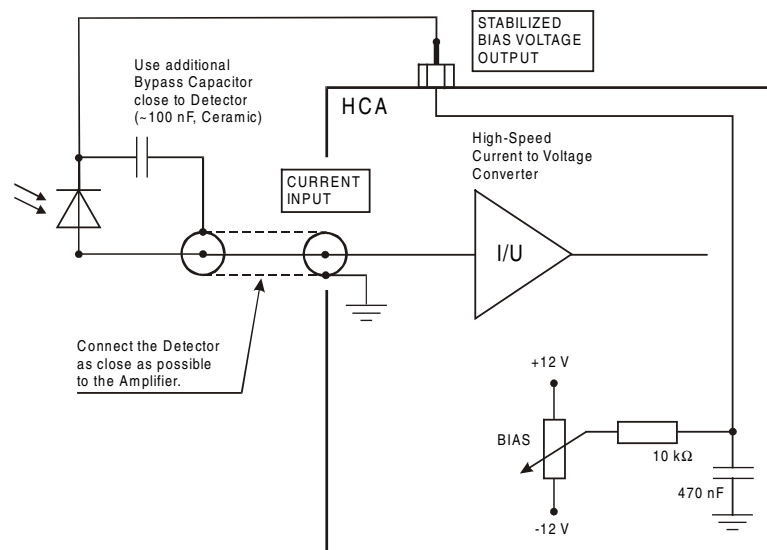
Connectors

Input	BNC
Output	BNC
Power Supply	LEMO series 1S, 3-pin fixed socket
	Pin 1: + 15V
	Pin 2: - 15V
	Pin 3: GND



Application Diagrams

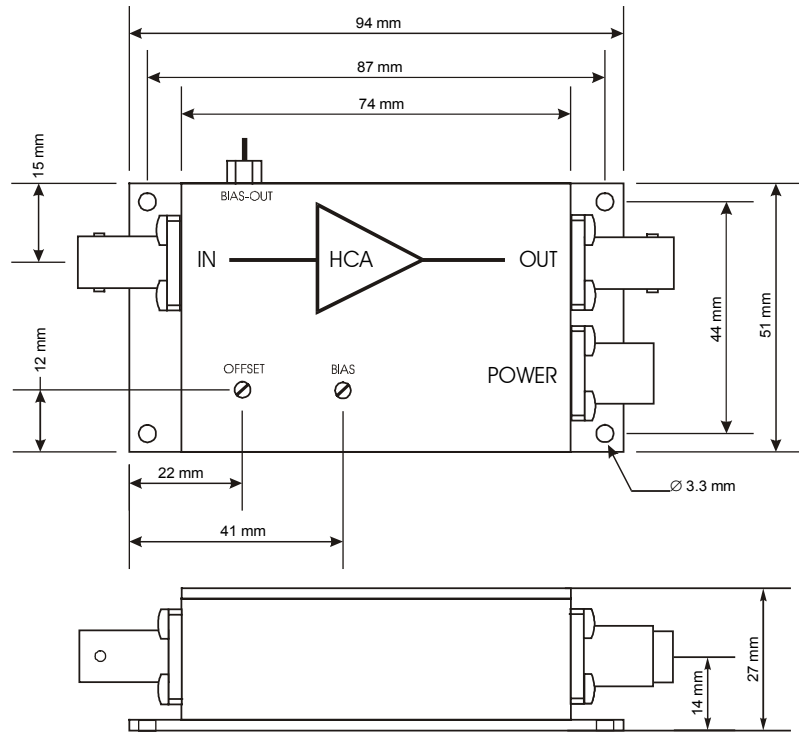
Photo Detector Biasing in Photoconductive Mode:  
Best choice for high speed applications and optimum signal to noise performance.



AZ01-0201-20

High Speed Current Amplifier

Dimensions



DZ01-0201-22

12/07 / V1 / HW / femto/current/ hca-1m-1m-c.pdf

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